

5-(4,5-Diiodo-1,3-dithiol-2-ylidene)-4',5'-bis(methylsulfanyl)-2,2'-bi-1,3-dithiol-4(5*H*)-one

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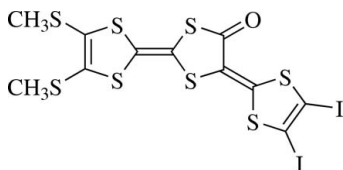
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Key indicators: single-crystal X-ray study; $T = 93$ K; mean $\sigma(\text{C}-\text{C}) = 0.004$ Å; R factor = 0.025; wR factor = 0.051; data-to-parameter ratio = 21.9.

The molecular framework of the title compound, $\text{C}_{11}\text{H}_6\text{I}_2\text{OS}_8$, is almost planar [maximum deviation = 0.057 (5) Å] except for the two methylsulfanyl groups, which are twisted relative to the molecular skeleton, with C—C—S—C torsion angles of 49.74 (22) and 82.91 (21)°. In the crystal, molecules are stacked alternately in opposite orientations, forming a one-dimensional column along the b axis. The interaction between adjacent columns is accomplished through $\text{S} \cdots \text{S}$ [3.4289 (5) Å], $\text{S} \cdots \text{I}$ [3.4498 (4) Å] and $\text{O} \cdots \text{I}$ [2.812 (2) Å] contacts.

Related literature

For background to tetrathiafulvalenoquinone-1,3-dithiol-emethide derivatives, see: Matsumoto *et al.* (2002*a,b*; 2003); Hiraoka *et al.* (2007); Sugimoto (2008). For the synthesis, see: Iwamatsu *et al.* (1999). For background to intermolecular $\text{I} \cdots \text{O}$ contacts, see: Etter (1976*a,b*); Groth & Hassel (1965); Leser & Rabinovich (1978). For van der Waals radii, see: Bondi (1964).



Experimental

Crystal data

$\text{C}_{11}\text{H}_6\text{I}_2\text{OS}_8$	$V = 1916.0$ (6) Å ³
$M_r = 664.44$	$Z = 4$
Monoclinic, $P2_1/n$	Mo $K\alpha$ radiation
$a = 7.7642$ (14) Å	$\mu = 4.15$ mm ⁻¹
$b = 17.652$ (3) Å	$T = 93$ K
$c = 14.124$ (3) Å	$0.10 \times 0.07 \times 0.03$ mm
$\beta = 98.188$ (2)°	

Data collection

Bruker APEXII CCD area-detector diffractometer	11092 measured reflections
Absorption correction: multi-scan (SADABS; Shelldrick, 1996)	4403 independent reflections
$T_{\min} = 0.682$, $T_{\max} = 0.886$	3764 reflections with $I > 2\sigma(I)$
	$R_{\text{int}} = 0.030$

Refinement

$R[F^2 > 2\sigma(F^2)] = 0.025$	201 parameters
$wR(F^2) = 0.051$	H-atom parameters constrained
$S = 0.99$	$\Delta\rho_{\text{max}} = 0.72$ e Å ⁻³
4403 reflections	$\Delta\rho_{\text{min}} = -0.56$ e Å ⁻³

Data collection: APEX2 (Bruker, 2006); cell refinement: SAINT (Bruker, 2006); data reduction: SAINT; program(s) used to solve structure: SHELXS97 (Sheldrick, 2008); program(s) used to refine structure: SHELXL97 (Sheldrick, 2008); molecular graphics: XSHL (Bruker, 2002); software used to prepare material for publication: XCIF (Bruker, 2001).

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: TK2544).

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Acta Cryst. (2009). E65, o2716 [doi:10.1107/S160053680904032X]

5-(4,5-Diiodo-1,3-dithiol-2-ylidene)-4',5'-bis(methylsulfanyl)-2,2'-bi-1,3-dithiol-4(5*H*)-one

K. Ueda and K. Yoza

Comment

New donor molecules featuring a skeleton of tetrathiafulvalenoquinone-1,3-dithiolemethide are used for the preparation of charge transfer (CT) salts with magnetic metal anions (Matsumoto *et al.*, 2002a,b, 2003; Hiraoka *et al.*, 2007; Sugimoto 2008). In CT salts these molecules can form unique crystal structures with channels in addition to the usual layer stacking structures as a result of their molecular skeletons and intermolecular S...S contacts. The introduction of iodide atoms as substituents in the molecular skeleton is expected to enhance intermolecular interaction through the formation of S...I and O...I heteroatom contacts. These contacts are of special interest in these structures as they may increase the dimensionality of aggregation in the solid-state. In this connection, the crystal structure of the title compound, (I), was investigated.

The molecular framework of (I), Fig. 1, except for two methylsulfanyl groups, is almost planar. The displacements of atoms S7, S8, I1, and I2 relative to the plane of the skeleton are 0.2056 (17), 0.230 (2), -0.1867 (15) and -0.1274 (18) Å, respectively. The torsion angles of the two methylsulfanyl groups are -49.74 (22)° for C11—S8—C9—S6 and -89.91 (21)° for C10—S7—C8—S5.

In the crystal structure, the molecules are alternatively stacked in opposite orientations to form a one-dimensional column along the *a* axis (Fig. 2). Stacked molecules are separated by interplanar distances greater than 3.54 Å and have fairly poor overlap. However, some effective side-by-side contacts are observed between molecules of adjacent columns. The interaction between adjacent columns is accomplished through contacts between different sulfur atoms [S2...S8ⁱ = 3.4289 (5) Å] along the *b* axis, between sulfur and iodide atoms [S7...I2ⁱⁱ = 3.4498 (4) Å] along the *c* axis, and between oxygen and iodide atoms [O1...I1ⁱⁱⁱ = 2.812 (2) Å] along the *b* axis; symmetry operation i: -1/2+x, 1/2-y, -1/2+z; ii: 1+x, y, 1+z; and iii: 1/2+x, -1/2-y, 1/2+z. These distances are shorter than the sum of corresponding van der Waals radii, i.e. 3.60 Å for S...S, 3.78 Å for S...I and 3.32 Å for O...I (Bondi, 1964). An interesting feature of this structure is the fairly shorter intermolecular O...I contacts. Such strong oxygen-halogen interactions have been observed previously (Groth & Hassel, 1965; Etter, 1976a,b). The intermolecular angles are 124.20 (19)° for C5=O1...I1 and 176.17 (10)° for O1...I1—C2 are fairly close to the ideal geometry (120° for C=O...I and 180° for O...I—C) which has been proposed for these types of associations (Leser & Rabinovich, 1978).

Experimental

Compound (I) was synthesized by a modification of the method used for the preparation of bis(methylsulfanyl)tetrathiafulvalenoquinone-1,3-dithiolemethide (Iwamatsu *et al.*, 1999). Bis(tetraethylammonium)bis(2,3-bis(methylsulfanyl)tetrathiafulvalenyl-6,7-dithiolato)zinc (269 mg, 0.258 mmol) was reacted with 4,5-diiodo-2-methylsulfanyl-1,3-dithiole-2,3-dithiolium tetrafluoroborate (535 mg, 1.10 mmol) in THF-DMF (5:1 = *v/v*) at room temperature under nitrogen and stirring for 12 h. After separation of the reaction mixture by column chromatography on silica gel (eluent: CS₂) followed by recrystallization from CS₂/*n*-hexane, bis(dimethylsulfanyl)tetrathiafulvalenothioquinone-4,5-diiodo-1,3-dithiolemethide (II) was obtained as a dark-green

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needles in 72% yield. When compound (II) (87 mg, 0.127 mmol) was reacted with mercury(II) acetate (90 mg, 0.282 mmol) in THF-AcOH (5:1 =v/v), compound (I) was obtained as a dark-red plates in 47% yield by recrystallization from CS₂/*n*-hexane.

Refinement

The H atoms were geometrically placed with C-H = 0.98 Å, and refined as riding with $U_{\text{iso}}(\text{H}) = 1.5U_{\text{eq}}(\text{C})$.

Figures

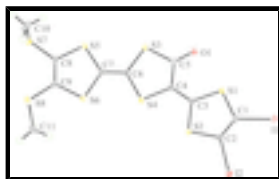


Fig. 1. The molecular structure of (I) showing atom labelling and 50% probability displacement ellipsoids for non-H atoms.

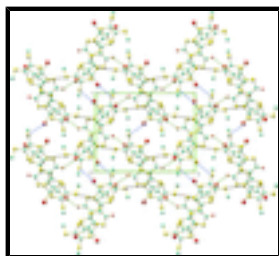


Fig. 2. Projection of the crystal packing in (I) down the *bc* plane. The S...S (black), S...I (blue) and O...I (green) contacts are shown with dashed lines.

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Crystal data

C₁₁H₆I₂OS₈

$M_r = 664.44$

Monoclinic, $P2_1/n$

$a = 7.7642$ (14) Å

$b = 17.652$ (3) Å

$c = 14.124$ (3) Å

$\beta = 98.188$ (2)°

$V = 1916.0$ (6) Å³

$Z = 4$

$F_{000} = 1256$

$D_x = 2.303$ Mg m⁻³

Mo $K\alpha$ radiation, $\lambda = 0.71073$ Å

Cell parameters from 3988 reflections

$\theta = 2.3$ – 27.5 °

$\mu = 4.15$ mm⁻¹

$T = 93$ K

Plate, dark-red

$0.10 \times 0.07 \times 0.03$ mm

Data collection

Bruker APEXII CCD area-detector diffractometer

4403 independent reflections

Radiation source: Bruker TXS fine-focus rotating anode

3764 reflections with $I > 2\sigma(I)$

Monochromator: Bruker Helios multilayer confocal mirror

$R_{\text{int}} = 0.030$

Detector resolution: 8.333 pixels mm⁻¹

$\theta_{\text{max}} = 27.6$ °

$T = 93$ K $\theta_{\min} = 1.9^\circ$
 φ and ω scans $h = -6 \rightarrow 10$
 Absorption correction: multi-scan (SADABS; Sheldrick, 1996) $k = -22 \rightarrow 22$
 $T_{\min} = 0.682$, $T_{\max} = 0.886$ $l = -18 \rightarrow 15$
 11092 measured reflections

Refinement

Refinement on F^2 Secondary atom site location: difference Fourier map
 Least-squares matrix: full Hydrogen site location: inferred from neighbouring sites
 $R[F^2 > 2\sigma(F^2)] = 0.025$ H-atom parameters constrained
 $wR(F^2) = 0.051$ $w = 1/[\sigma^2(F_o^2) + (0.019P)^2]$
 where $P = (F_o^2 + 2F_c^2)/3$
 $S = 0.99$ $(\Delta/\sigma)_{\max} = 0.006$
 4403 reflections $\Delta\rho_{\max} = 0.72 \text{ e } \text{\AA}^{-3}$
 201 parameters $\Delta\rho_{\min} = -0.56 \text{ e } \text{\AA}^{-3}$
 Primary atom site location: structure-invariant direct methods Extinction correction: none

Special details

Geometry. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R -factor wR and goodness of fit S are based on F^2 , conventional R -factors R are based on F , with F set to zero for negative F^2 . The threshold expression of $F^2 > \sigma(F^2)$ is used only for calculating R -factors(gt) *etc.* and is not relevant to the choice of reflections for refinement. R -factors based on F^2 are statistically about twice as large as those based on F , and R -factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (\AA^2)

	x	y	z	$U_{\text{iso}}^*/U_{\text{eq}}$
I2	-0.12578 (3)	0.013561 (12)	0.111820 (14)	0.01793 (6)
I1	-0.15011 (3)	-0.203405 (12)	0.164968 (14)	0.01569 (6)
C9	0.6068 (4)	0.19937 (18)	0.7771 (2)	0.0152 (7)
C1	-0.0462 (4)	-0.11760 (18)	0.2570 (2)	0.0149 (7)
C6	0.4087 (4)	0.01803 (18)	0.6428 (2)	0.0136 (6)
C4	0.2274 (4)	-0.04697 (17)	0.4954 (2)	0.0120 (6)
C8	0.6498 (4)	0.14725 (18)	0.8460 (2)	0.0154 (7)
C2	-0.0379 (4)	-0.04383 (18)	0.2381 (2)	0.0143 (7)
C3	0.1281 (4)	-0.06019 (17)	0.4091 (2)	0.0123 (6)
C7	0.4882 (4)	0.07062 (18)	0.7018 (2)	0.0142 (7)
C5	0.2707 (4)	-0.10758 (18)	0.5631 (2)	0.0142 (6)
S6	0.49464 (10)	0.16647 (5)	0.66722 (6)	0.01662 (17)

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S4	0.30314 (10)	0.04434 (4)	0.52857 (5)	0.01454 (16)
S2	0.06947 (10)	0.01342 (4)	0.32957 (5)	0.01350 (16)
S7	0.75758 (11)	0.16499 (5)	0.96192 (6)	0.02020 (18)
S5	0.59033 (10)	0.05246 (5)	0.81921 (6)	0.01688 (17)
S3	0.39758 (10)	-0.07854 (5)	0.67194 (6)	0.01666 (17)
S1	0.05054 (10)	-0.14886 (4)	0.36963 (6)	0.01449 (17)
S8	0.63332 (11)	0.29739 (5)	0.79188 (6)	0.02255 (19)
O1	0.2235 (3)	-0.17383 (12)	0.54846 (15)	0.0180 (5)
C11	0.7178 (5)	0.3241 (2)	0.6839 (3)	0.0263 (8)
H13A	0.8305	0.2994	0.6825	0.039*
H13B	0.7326	0.3792	0.6825	0.039*
H13C	0.6362	0.3081	0.6280	0.039*
C10	0.5747 (5)	0.1720 (2)	1.0279 (2)	0.0303 (9)
H12A	0.5026	0.2156	1.0045	0.045*
H12B	0.6174	0.1787	1.0960	0.045*
H12C	0.5051	0.1256	1.0187	0.045*

Atomic displacement parameters (\AA^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
I2	0.01932 (12)	0.02057 (12)	0.01307 (11)	0.00006 (9)	-0.00063 (8)	0.00219 (8)
I1	0.01529 (11)	0.01492 (11)	0.01614 (11)	-0.00063 (8)	-0.00027 (8)	-0.00382 (8)
C9	0.0150 (16)	0.0153 (17)	0.0153 (16)	-0.0013 (13)	0.0020 (12)	-0.0021 (13)
C1	0.0128 (15)	0.0164 (17)	0.0153 (16)	-0.0002 (13)	0.0014 (12)	-0.0051 (13)
C6	0.0140 (15)	0.0145 (17)	0.0117 (15)	0.0028 (13)	-0.0003 (12)	0.0016 (12)
C4	0.0151 (15)	0.0091 (16)	0.0122 (15)	0.0011 (12)	0.0028 (12)	-0.0019 (12)
C8	0.0142 (16)	0.0163 (17)	0.0156 (17)	-0.0025 (13)	0.0019 (13)	-0.0050 (13)
C2	0.0120 (15)	0.0183 (18)	0.0118 (16)	-0.0014 (13)	-0.0016 (12)	0.0003 (13)
C3	0.0119 (15)	0.0114 (16)	0.0141 (16)	0.0013 (12)	0.0038 (12)	0.0009 (12)
C7	0.0119 (15)	0.0174 (17)	0.0136 (16)	-0.0007 (12)	0.0029 (12)	-0.0011 (13)
C5	0.0103 (15)	0.0164 (17)	0.0165 (16)	0.0033 (12)	0.0037 (12)	0.0009 (13)
S6	0.0201 (4)	0.0142 (4)	0.0148 (4)	-0.0009 (3)	0.0000 (3)	-0.0002 (3)
S4	0.0172 (4)	0.0111 (4)	0.0143 (4)	-0.0004 (3)	-0.0011 (3)	-0.0005 (3)
S2	0.0170 (4)	0.0104 (4)	0.0123 (4)	-0.0004 (3)	-0.0005 (3)	0.0008 (3)
S7	0.0217 (4)	0.0225 (5)	0.0151 (4)	-0.0016 (4)	-0.0021 (3)	-0.0028 (3)
S5	0.0198 (4)	0.0152 (4)	0.0149 (4)	-0.0016 (3)	-0.0003 (3)	-0.0011 (3)
S3	0.0206 (4)	0.0137 (4)	0.0143 (4)	-0.0007 (3)	-0.0023 (3)	0.0011 (3)
S1	0.0175 (4)	0.0101 (4)	0.0150 (4)	0.0002 (3)	-0.0009 (3)	-0.0004 (3)
S8	0.0317 (5)	0.0141 (4)	0.0218 (5)	-0.0030 (4)	0.0036 (4)	-0.0037 (3)
O1	0.0220 (12)	0.0136 (12)	0.0170 (12)	-0.0005 (10)	-0.0016 (9)	0.0008 (9)
C11	0.032 (2)	0.0164 (19)	0.031 (2)	-0.0020 (15)	0.0087 (16)	0.0030 (15)
C10	0.036 (2)	0.036 (2)	0.0183 (19)	0.0172 (18)	0.0010 (15)	-0.0053 (16)

Geometric parameters (\AA , $^\circ$)

I2—C2	2.080 (3)	C2—S2	1.755 (3)
I1—C1	2.082 (3)	C3—S2	1.736 (3)
C9—C8	1.347 (4)	C3—S1	1.740 (3)
C9—S8	1.751 (3)	C7—S6	1.764 (3)

C9—S6	1.766 (3)	C7—S5	1.763 (3)
C1—C2	1.333 (4)	C5—O1	1.234 (4)
C1—S1	1.749 (3)	C5—S3	1.780 (3)
C6—C7	1.338 (4)	S7—C10	1.810 (4)
C6—S3	1.759 (3)	S8—C11	1.807 (4)
C6—S4	1.765 (3)	C11—H13A	0.9800
C4—C3	1.366 (4)	C11—H13B	0.9800
C4—C5	1.442 (4)	C11—H13C	0.9800
C4—S4	1.756 (3)	C10—H12A	0.9800
C8—S7	1.757 (3)	C10—H12B	0.9800
C8—S5	1.763 (3)	C10—H12C	0.9800
C8—C9—S8	125.2 (2)	O1—C5—C4	123.8 (3)
C8—C9—S6	116.8 (2)	O1—C5—S3	122.1 (2)
S8—C9—S6	117.69 (18)	C4—C5—S3	114.0 (2)
C2—C1—S1	117.6 (2)	C7—S6—C9	95.85 (15)
C2—C1—I1	127.7 (2)	C4—S4—C6	95.57 (15)
S1—C1—I1	114.61 (17)	C3—S2—C2	95.67 (15)
C7—C6—S3	124.1 (2)	C8—S7—C10	100.80 (15)
C7—C6—S4	120.0 (2)	C8—S5—C7	95.65 (15)
S3—C6—S4	115.91 (17)	C6—S3—C5	96.70 (15)
C3—C4—C5	120.9 (3)	C3—S1—C1	95.27 (14)
C3—C4—S4	121.3 (2)	C9—S8—C11	101.97 (16)
C5—C4—S4	117.8 (2)	S8—C11—H13A	109.5
C9—C8—S7	126.0 (3)	S8—C11—H13B	109.5
C9—C8—S5	117.6 (2)	H13A—C11—H13B	109.5
S7—C8—S5	116.41 (18)	S8—C11—H13C	109.5
C1—C2—S2	116.5 (2)	H13A—C11—H13C	109.5
C1—C2—I2	128.9 (2)	H13B—C11—H13C	109.5
S2—C2—I2	114.47 (17)	S7—C10—H12A	109.5
C4—C3—S2	120.8 (2)	S7—C10—H12B	109.5
C4—C3—S1	124.4 (2)	H12A—C10—H12B	109.5
S2—C3—S1	114.77 (16)	S7—C10—H12C	109.5
C6—C7—S6	121.5 (2)	H12A—C10—H12C	109.5
C6—C7—S5	124.4 (3)	H12B—C10—H12C	109.5
S6—C7—S5	114.10 (17)		

Fig. 1

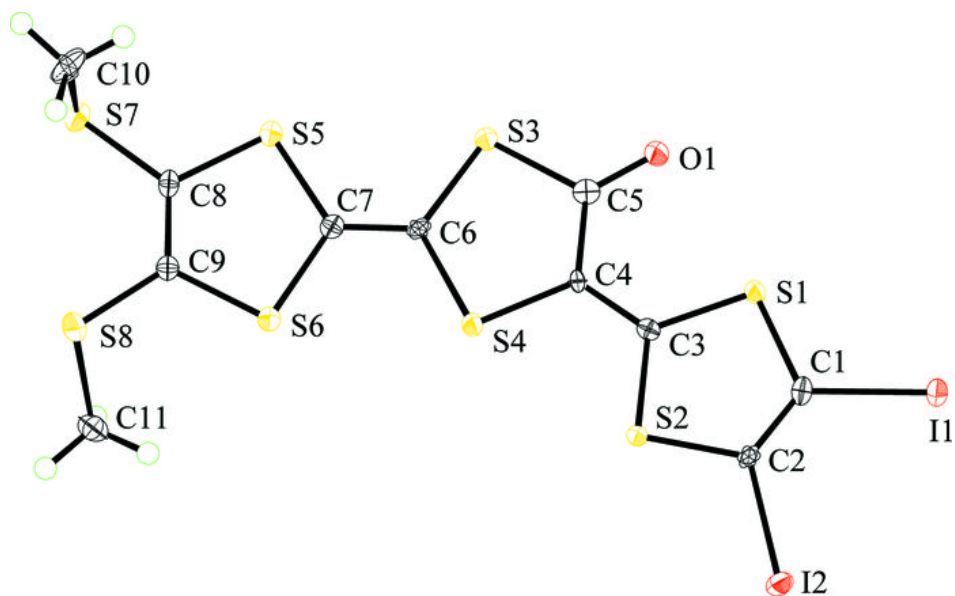


Fig. 2

